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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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AH3781

HIGH-VOLTAGE HIGH-SENSITIVITY HALL EFFECT LATCH WITH INTERNAL PULL-UP RESISTOR

Description

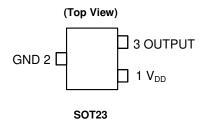
The AH3781 is a high-voltage, high-sensitivity Hall Effect latch IC with internal pull-up resistor designed for commutation of brushless DC motors, flow meters, linear encoders and position sensors in industrial, consumer home appliance and personal care applications. To support a wide range of demanding applications, the design is optimized to operate over the supply range of 3.0V to 28V. With chopper stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3781 provides a reliable solution over the whole operating range. For robustness and protection, the device has a Zener clamp on the supply. The output has an overcurrent limit and a Zener clamp.

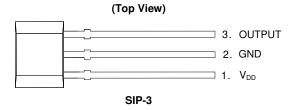
The internally pulled-up output can be switched on with South pole of sufficient strength and switched off with North pole of sufficient strength. When the magnetic flux density (B) perpendicular to the part marking surface is larger than the operate point (B_{OP}) the output is switched on (pulled low). The output is held latched until magnetic flux density reverses and becomes lower than the release point (B_{BP}).

Features

- Bipolar Latch Operation (South Pole: On, North Pole: off)
- · 3.0V to 28V Operating Voltage Range
- High Sensitivity: B_{OP} and B_{RP} of +25G and -25G Typical
- Internally Pull-up Resistor on the Output Pin
- Output Overcurrent Limit
- Chopper Stabilized Design Provides
 - Superior Temperature Stability
 - Minimal Switch Point Drift
 - Enhanced Immunity to Stress
- Good RF Noise Immunity
- Zener Clamp on Supply and Output Pins
- -40°C to +125°C Operating Temperature
- ESD (HBM): 6kV
- · Industry Standard SOT23 and SIP-3 Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments





Applications

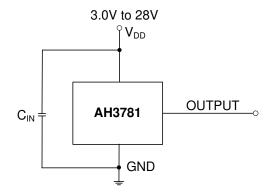
- · Brushless DC Motor Commutation
- Revolution Per Minute (RPM) Measurement
- · Flow Meters
- Angular and Linear Encoder and Position Sensors
- Contactless Commutation, Speed Measurement and Angular Position Sensing/Indexing in Consumer Home Appliances, Office Equipments and Industrial Applications

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit



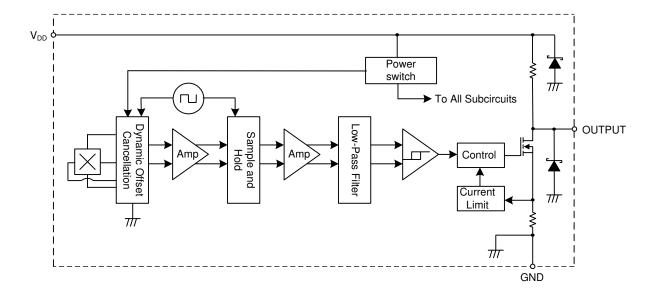
Note: 4. C_{IN} is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 10nF ~ 100nF. R_L is the pull-up resistor.

Pin Descriptions

Package: SOT23

Pin Number	Pin Name	Function				
1	V_{DD}	Power Supply Input				
2	GND	Ground				
3	OUTPUT	Output Pin				

Functional Block Diagram





Absolute Maximum Ratings (Notes 5 & 6) (@T_A = +25°C, unless otherwise specified.)

Symbol	Characteristic		Value	Unit
V_{DD}	Supply Voltage (Note 6)		32	V
V_{DDR}	Reverse Supply Voltage		-0.3	V
V _{OUT_MAX}	Output Off Voltage (Note 6)		32V	V
I _{OUT}	Continuous Output Current	60	mA	
В	Magnetic Flux Density	Unlimited		
В	Package Power Dissipation	SIP-3	550	mW
P_{D}	Fackage Fower Dissipation	SOT23	230	mW
Ts	Storage Temperature Range	-65 to +165	°C	
TJ	Maximum Junction Temperature	+150	°C	
ESD	Electrostatic Discharge Withstand Capability - Human Body N	1odel	6	kV

Notes:

- 5. Stresses greater than the 'Absolute Maximum Ratings' specified above may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.
- 6. The absolute maximum V_{DD} of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

Recommended Operating Conditions (@T_A = -40°C to +125°C, unless otherwise specified.)

Symbol	Parameter	Parameter Conditions			
V_{DD}	Supply Voltage	Operating	3.0 to 28	V	
T _A	Operating Temperature Range	Operating	-40 to +125	°C	

Electrical Characteristics (Note 7 & 8) (@T_A = -40°C to +125°C, V_{DD} = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OUT_ON}	Output On Voltage	I _{OUT} = 20mA, B > B _{OP}	-	0.2	0.4	٧
lout_off	Output Leakage Current	V _{OUT} = 28V, B < B _{RP} , Output off	-	<0.1	15	μΑ
I _{DD}	Supply Current	Output open, V _{DD} = 12V , T _A = +25°C	-	3.8	4.9	mA
		Output open, T _A = -40°C to +125°C	-	3.8	5.8	mA
R_{PU}	Internal Pull-Up Resistance	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	10	14	18	kΩ
t _{ST}	Device Start-Up Time	$V_{DD} >= 3V, B > B_{OP} (Note 7)$	-	10		μs
f _c	Chopping Frequency	$V_{DD} = 3V$ to 28V	-	800	-	kHz
t _d	The time delay from magnetic threshold reached to the start of the output rise or fall	(Note 9)	-	3.75	-	μs
t _r	Output Rising Time (external pull-up resistor R∟and load capacitance dependent)	$R_L = 1k\Omega$, $C_L = 20pF$	-	0.2	1	μѕ
t _f	Output Falling Time (Internal switch resistance and load capacitance dependent)	$R_L = 1k\Omega$, $C_L = 20pF$	-	0.1	1	μs
locl	Output Current Limit	B > B _{OP} , (Note 10)	30	-	55	mA
Vz	Zener Clamp Voltage	$I_{DD} = 5mA$	28	-	-	٧

Notes:

- 7. When power is initially turned on, V_{DD} must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10μs typical from the operating voltage reaching 3V.
- 8. Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization
- 9. Guaranteed by design, process control and characterization. Not tested in production.
- 10. The device will limit the output current lour to current limit of lock.

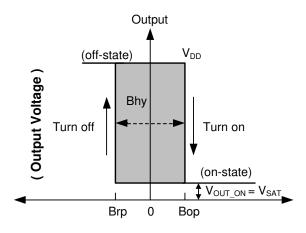


Magnetic Characteristics (Notes 11 &12) (T_A = -40°C to +125°C, V_{DD} = 3.0V to 28V, unless otherwise specified)

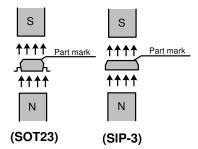
				(1mT=10 G	auss)
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
D (Courth note to nort marking side)	Operation Point	$V_{DD} = 12V, T_A = +25^{\circ}C$	-	25	-	
B _{OP} (South pole to part marking side)	Operation Foint	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	10	25	40	
D (North pole to part marking side)	Release Point	$V_{DD} = 12V, T_A = +25^{\circ}C$	-	-25	-	Gauss
B _{RP} (North pole to part marking side)	nelease Follit	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	-40	-25	-10	Gauss
P (P P)	Hystorosia (Noto 12)	$V_{DD} = 12V, T_A = +25^{\circ}C$		50	-	
B _{HY} (B _{OPX} - B _{RPX})	Hysteresis (Note 13)	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	20	50	80	

Notes:

- 11. When power is initially turned on, V_{DD} must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.
- 12. Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization
- 13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization.



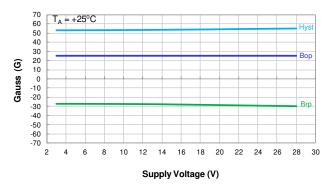
(Magnetic Flux Density B)



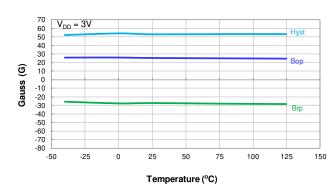


Typical Operating Characteristics

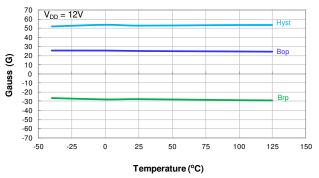
Magnetic Operating Switch Points - BOP and BRP



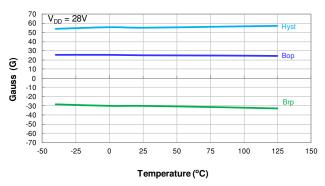
Switch Points Bop and Brp vs Supply Voltage



Switch Points Bop and Brp vs Temperature

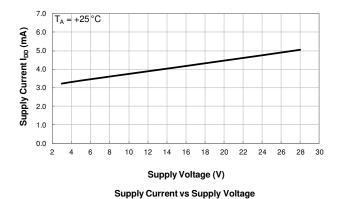


Switch Points Bop and Brp vs Temperature



Switch Points Bop and Brp vs Temperature

Supply Current



6.0 5.0 4.0 3.0 -20 -10 0 10 20 30 40 50 60 70 80 90 100 110 120 130

Temperature (°C)

Supply Current vs Temperature

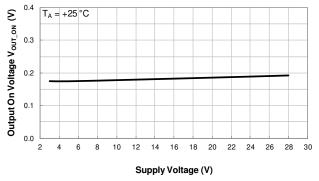
7.0

28V

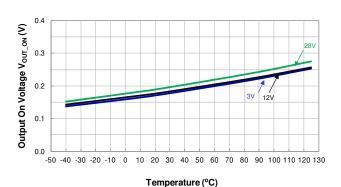


Typical Operating Characteristics

Output Switch On Voltage

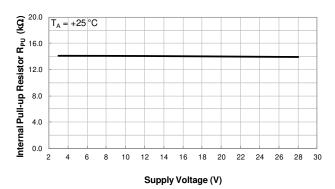


Output On Voltage vs Supply Voltage

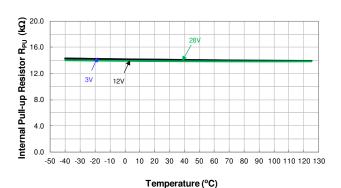


Output On Voltage vs Temperature

Output Pull-Up Resistor (Internal)

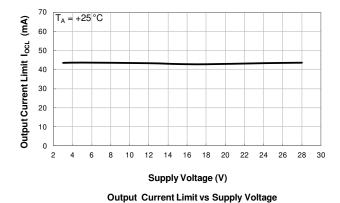


Internal Output Pull-up Resistor vs Supply Voltage



Internal Output Pull-up Resistor vs Temperature

Output Current Limit



Temperature (°C)

Output Current Limit vs Temperature

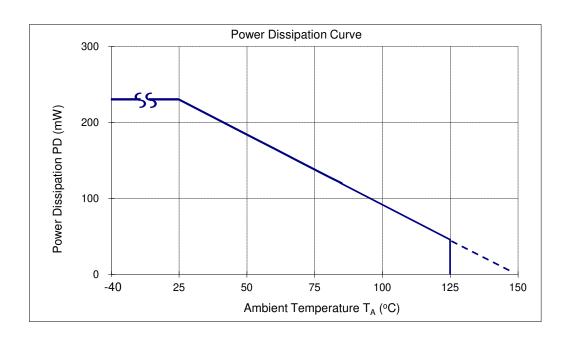
60



Thermal Performance Characteristics

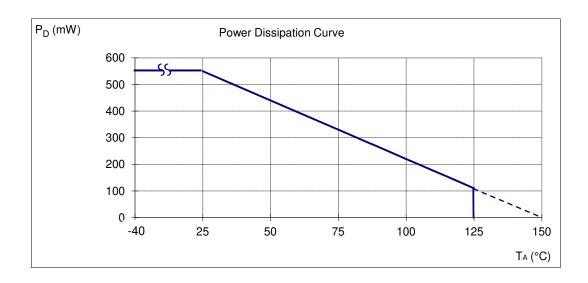
(1) Package Type: SOT23

T _A (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0



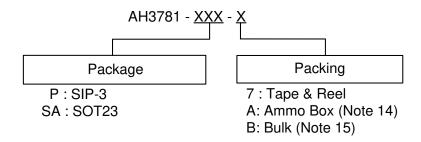
(2) Package type: SIP-3

T _A (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0





Ordering Information

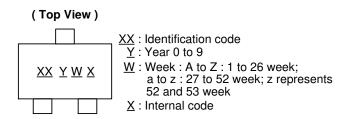


	Package Packa		ackaging Bulk		7" Tape an	d Reel	Ammo Box		
Part Number	Code	rackaging	Quantity	Part Number Suffix	Quantity	Part Number Suffix	Quantity	Part Number Suffix	
AH3781-P-A	Р	SIP-3	NA	NA	NA	NA	4,000/Box	-A	
AH3781-P-B	Р	SIP-3	1,000	-B	NA	NA	NA	NA	
AH3781-SA-7	SA	SOT23	NA	NA	3,000/Tape & Reel	-7	NA	NA	

14. Ammo Box is for SIP-3 Spread Lead.15. Bulk is for SIP-3 Straight Lead. Notes:

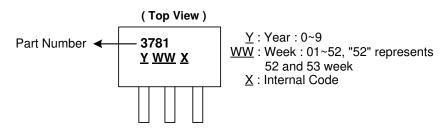
Marking Information

(1) Package Type: SOT23



Part Number	Package	Identification Code
AH3781	SOT23	WX

(2) Package Type: SIP-3



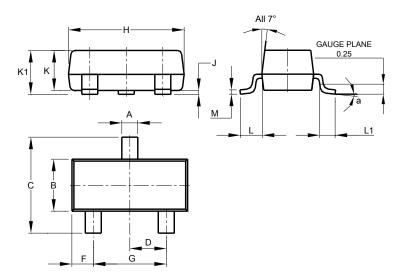
Part Number	Package	Identification Code
AH3781	SIP-3	3781



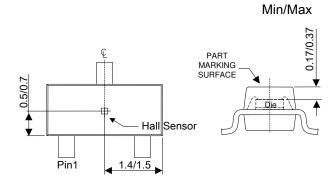
Package Outline Dimensions (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(1) Package Type: SOT23



	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а		8°	•					
All	Dimens	ions in	mm					



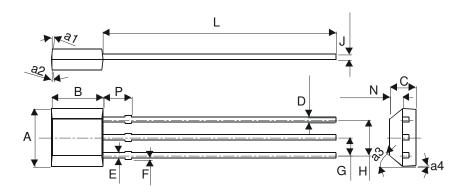
Sensor Location



Package Outline Dimensions (cont.) (All dimensions in mm.)

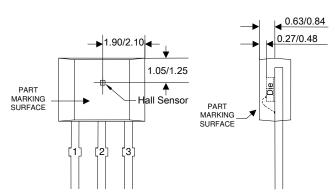
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(2) Package Type: SIP-3 Bulk



Ş	SIP-3 (Bu	lk)
Dim	Min	Max
Α	3.9	4.3
a1	5°	Тур
a2	5°	Тур
а3	45°	[,] Typ
a4	3°	Тур
В	2.8	3.2
С	1.40	1.60
D	0.33	0.432
Е	0.40	0.508
F	0	0.2
G	1.24	1.30
Н	2.51	2.57
J	0.35	0.43
L	14.0	15.0
N	0.63	0.84
Р	1.55	-
All Di	mension	s in mm





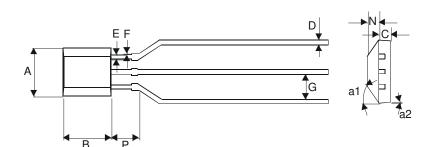
Sensor Location



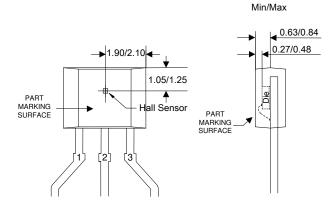
Package Outline Dimensions (cont.) (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(3) Package Type: SIP-3 Ammo Pack



SIP-3 (Ammo Pack)		
Dim	Min	Max
Α	3.9	4.3
a1	45° Typ	
a2	3° Тур	
В	2.8	3.2
C	1.40	1.60
D	0.35	0.41
Е	0.43	0.48
F	0	0.2
G	2.4	2.9
N	0.63	0.84
Р	1.55	-
All Dimensions in mm		

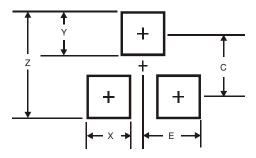


Sensor Location



Suggested Pad Layout
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(1) Package Type: SOT23



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Υ	0.9
С	2.0
E	1.35



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